

### FAST RECOVERY DIODES

Stud Version

#### Features

- High power FAST recovery diode series
- 1.0 to 2.0  $\mu$ s recovery time
- High voltage ratings up to 2500V
- High current capability
- Optimized turn on and turn off characteristics
- Low forward recovery
- Fast and soft reverse recovery
- Compression bonded encapsulation
- Stud version JEDEC DO-205AB (DO-9)
- Maximum junction temperature 125°C
- RoHS Compliant

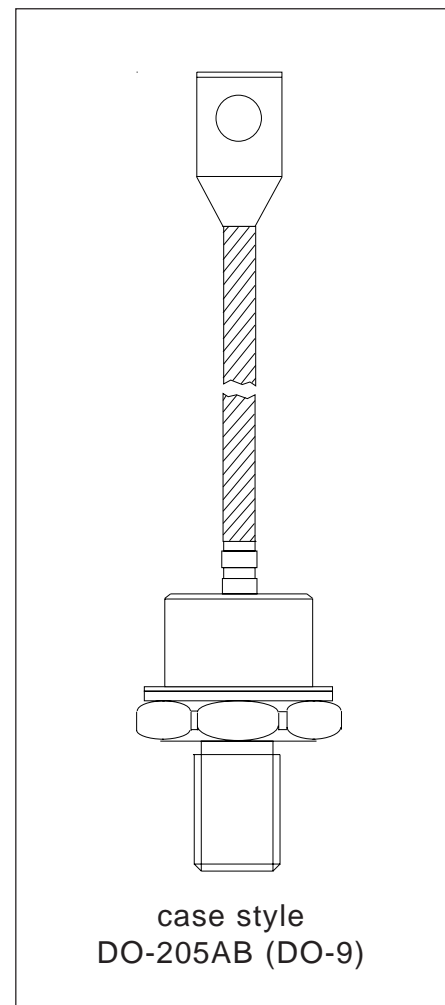
200A

#### Typical Applications

- Snubber diode for GTO
- High voltage free-wheeling diode
- Fast recovery rectifier applications

#### Major Ratings and Characteristics

Parameters	SD203N/R	Units
$I_{F(AV)}$	200	A
@ $T_C$	85	°C
$I_{F(RMS)}$	314	A
$I_{FSM}$ @ 50Hz	4990	A
@ 60Hz	5230	A
$I^2t$ @ 50Hz	125	KA <sup>2</sup> s
@ 60Hz	114	KA <sup>2</sup> s
$V_{RRM}$ range	400 to 2500	V
$t_{rr}$ range	1.0 to 2.0	$\mu$ s
@ $T_J$	25	°C
$T_J$	- 40 to 125	°C



**ELECTRICAL SPECIFICATIONS**

**Voltage Ratings**

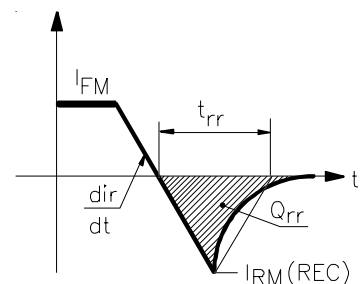
Type number	Voltage Code	$V_{RRM}$ max. repetitive peak and off-state voltage V	$V_{RSM}$ , maximum non-repetitive peak voltage V	$I_{RRM}$ max. $T_J = 125^\circ\text{C}$ mA
SD203N/R..S10	04	400	500	35
	08	800	900	
	10	1000	1100	
SD203N/R..S15	12	1200	1300	
	14	1400	1500	
	16	1600	1700	
SD203N/R..S20	20	2000	2100	
	25	2500	2600	

**Forward Conduction**

Parameter	SD203N/R	Units	Conditions
$I_{F(AV)}$ Max. average forward current @ Case temperature	200	A	180° conduction, half sine wave.
	85	°C	
$I_{F(RMS)}$ Max. RMS current	314	A	DC @ 76°C case temperature
$I_{FSM}$ Max. peak, one-cycle non-repetitive forward current	4990	A	t = 10ms No voltage
	5230		t = 8.3ms reappplied
	4200		t = 10ms 100% $V_{RRM}$
	4400		t = 8.3ms reappplied
$I^2t$ Maximum $I^2t$ for fusing	125	KA <sup>2</sup> s	t = 10ms No voltage
	114		t = 8.3ms reappplied
	88		t = 10ms 100% $V_{RRM}$
	81		t = 8.3ms reappplied
$I^2\sqrt{t}$ Maximum $I^2\sqrt{t}$ for fusing	1250	KA <sup>2</sup> √s	t = 0.1 to 10ms, no voltage reappplied
$V_{F(TO)1}$ Low level of threshold voltage	1.00	V	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J \text{ max.}$
$V_{F(TO)2}$ High level of threshold voltage	1.47		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J \text{ max.}$
$r_{f1}$ Low level of forward slope resistance	1.10	mΩ	$(16.7\% \times \pi \times I_{F(AV)} < I < \pi \times I_{F(AV)})$ , $T_J = T_J \text{ max.}$
$r_{f2}$ High level of forward slope resistance	0.46		$(I > \pi \times I_{F(AV)})$ , $T_J = T_J \text{ max.}$
$V_{FM}$ Max. forward voltage	1.65	V	$I_{pk} = 628\text{A}$ , $T_J = 25^\circ\text{C}$ , $t_p = 400 \mu\text{s}$ square pulse

**Recovery Characteristics**

Code	$T_J = 25^\circ\text{C}$ typical $t_{rr}$ @ 25% $I_{RRM}$ (μs)	Testconditions			Max. values @ $T_J = 125^\circ\text{C}$		
		$I_{pk}$ Square Pulse (A)	$di/dt$ (A/μs)	$V_r$ (V)	$t_{rr}$ @ 25% $I_{RRM}$ (μs)	$Q_{rr}$ (μC)	$I_{rr}$ (A)
S10	1.0	750	25	-30	2.4	52	33
S15	1.5				2.9	90	44
S20	2.0				3.2	107	46



### Thermal and Mechanical Specification

Parameter	SD203N/R	Units	Conditions
T <sub>J</sub> Max. operating temperature range	-40 to 125	°C	
T <sub>stg</sub> Max. storage temperature range	-40 to 150		
R <sub>thJC</sub> Max. thermal resistance, junction to case	0.115	K/W	DC operation
R <sub>thCS</sub> Max. thermal resistance, case to heatsink	0.08		Mounting surface, smooth, flat and greased
T Mounting torque ±10%	31	N m	Not lubricated threads
	24.5		Lubricated threads
wt Approximate weight	250	g	
Case style	DO-205AB (DO-9)		See Outline Table

### ΔR<sub>thJC</sub> Conduction

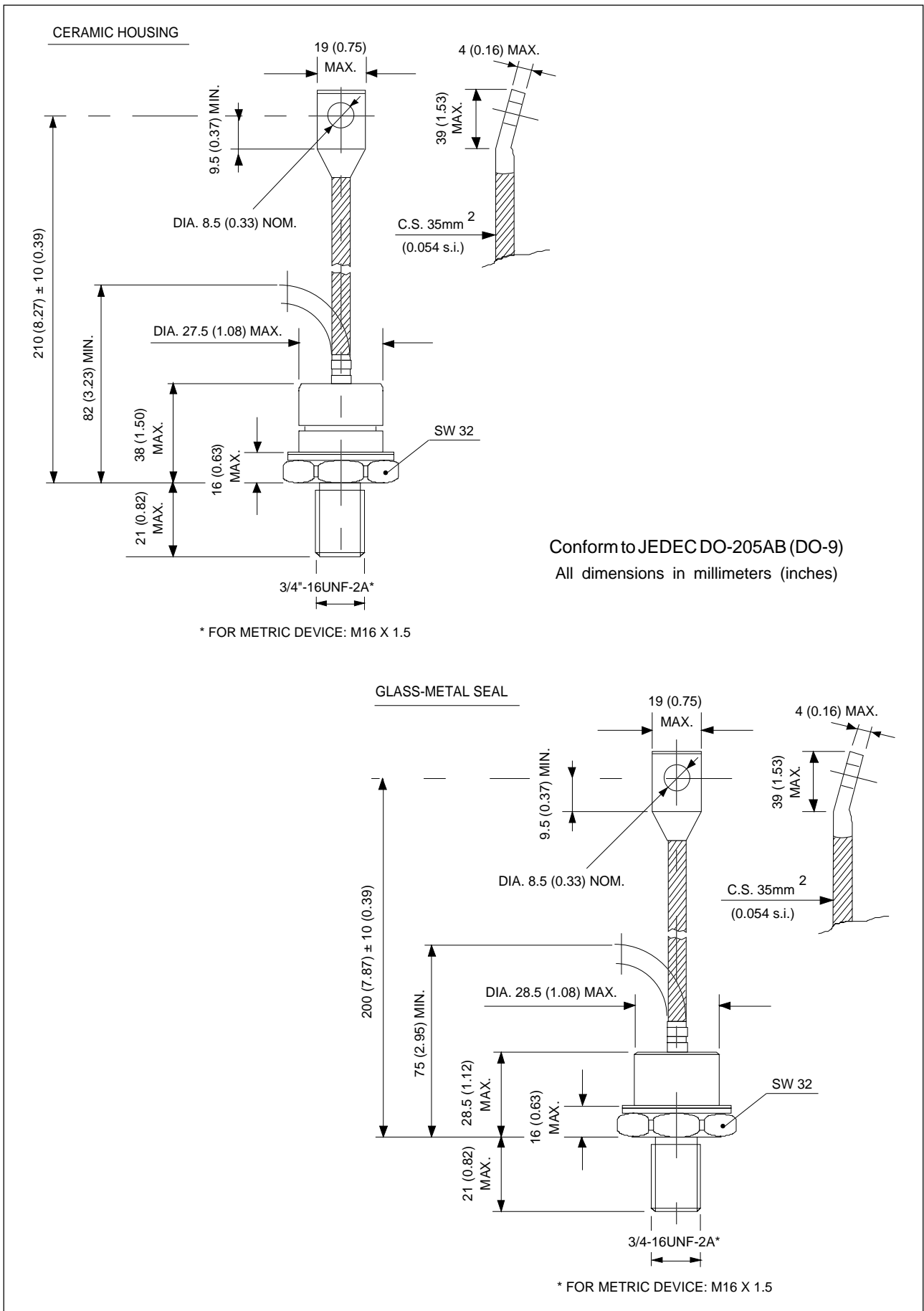
(The following table shows the increment of thermal resistance R<sub>thJC</sub> when devices operate at different conduction angles than DC)

Conduction angle	Sinusoidal conduction	Rectangular conduction	Units	Conditions
180°	0.010	0.008	K/W	T <sub>J</sub> = T <sub>J</sub> max.
120°	0.013	0.014		
90°	0.017	0.019		
60°	0.025	0.027		
30°	0.044	0.044		

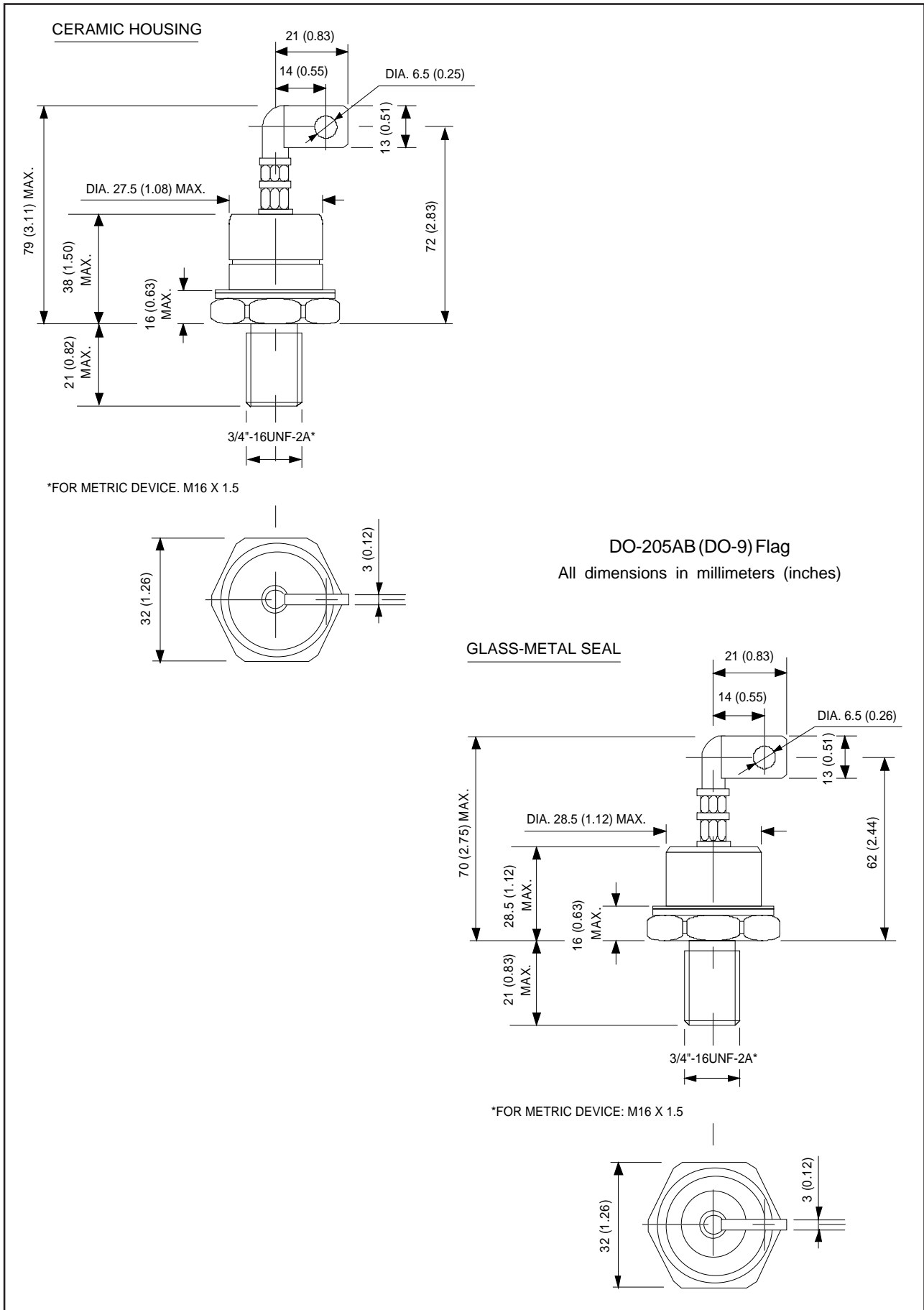
### Ordering Information Table

Device Code	
SD 20 3 R 25 S20 P B C	
① ② ③ ④ ⑤ ⑥ ⑦ ⑧ ⑨	
<b>1</b>	- Diode
<b>2</b>	- Essential part number
<b>3</b>	- 3 = Fast recovery
<b>4</b>	- N = Stud Normal Polarity (Cathode to Stud) R = Stud Reverse Polarity (Anode to Stud)
<b>5</b>	- Voltage code: Code x 100 = V <sub>RRM</sub> (see Voltage Ratings table)
<b>6</b>	- t <sub>rr</sub> code (see Recovery Characteristics table)
<b>7</b>	- P = Stud base DO-205AB (DO-9) 3/4" 16UNF-2A M = Stud base DO-205AB (DO-9) M16 X 1.5
<b>8</b>	- B = Flag top terminals (for Cathode/ Anode Leads) S = Isolated lead with silicone sleeve (Red = Reverse Polarity; Blue = Normal Polarity) None = Not isolated lead
<b>9</b>	- C = Ceramic housing (over 1600V) V = Glass-metal seal (only up to 1600V)

**Outline Table**



Outline Table



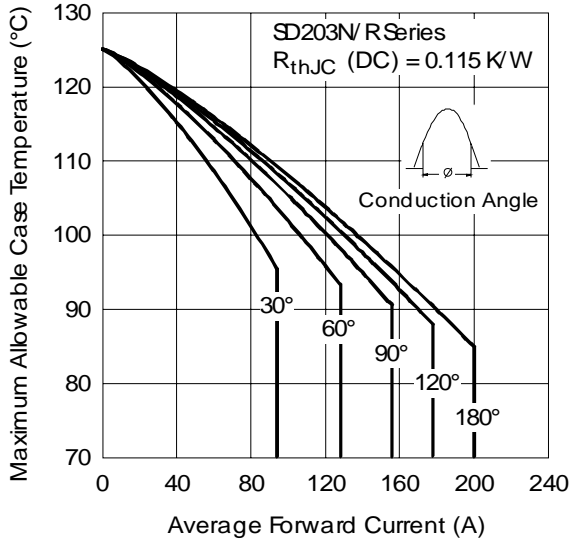


Fig. 1 - Current Ratings Characteristics

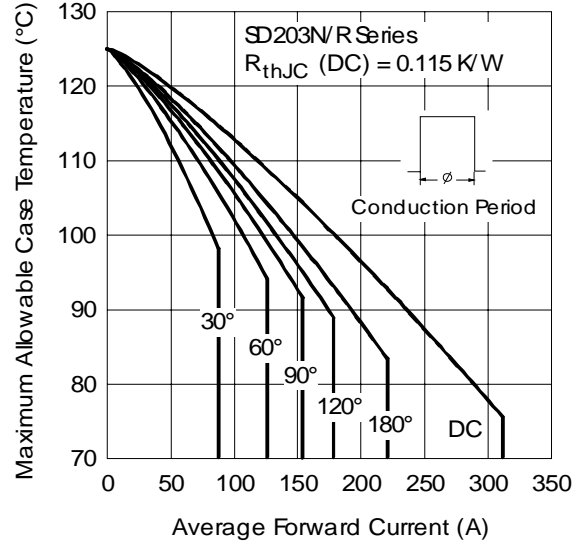


Fig. 2 - Current Ratings Characteristics

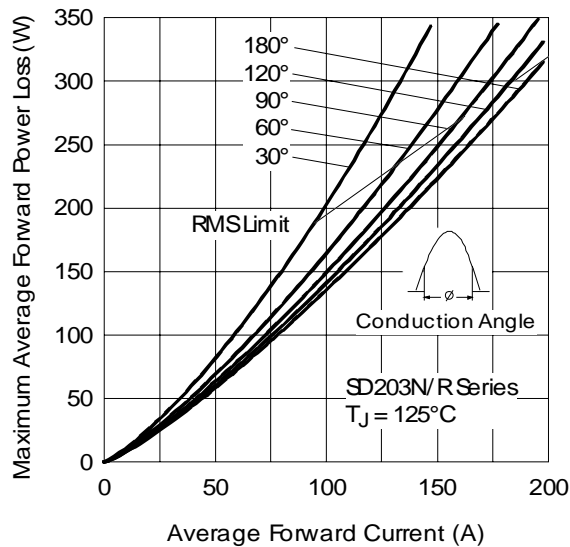


Fig. 3 - Forward Power Loss Characteristics

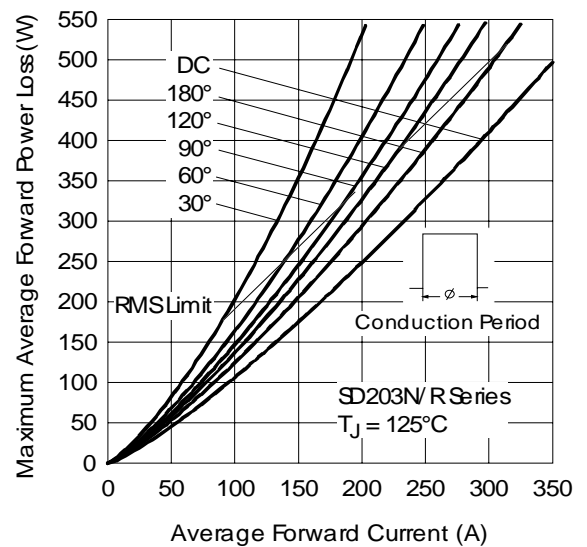


Fig. 4 - Forward Power Loss Characteristics

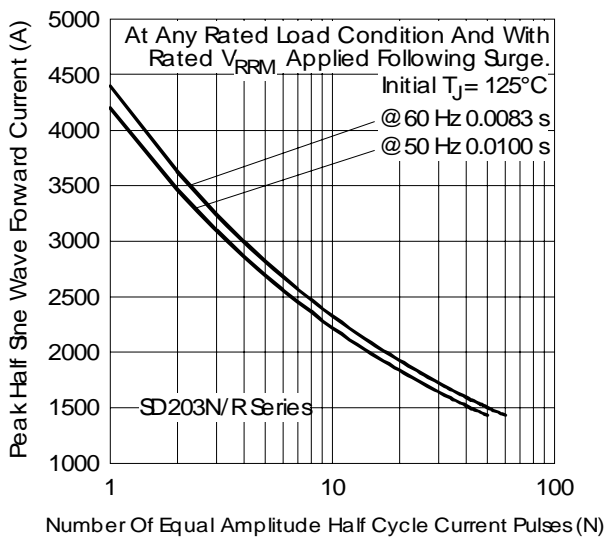


Fig. 5 - Maximum Non-repetitive Surge Current

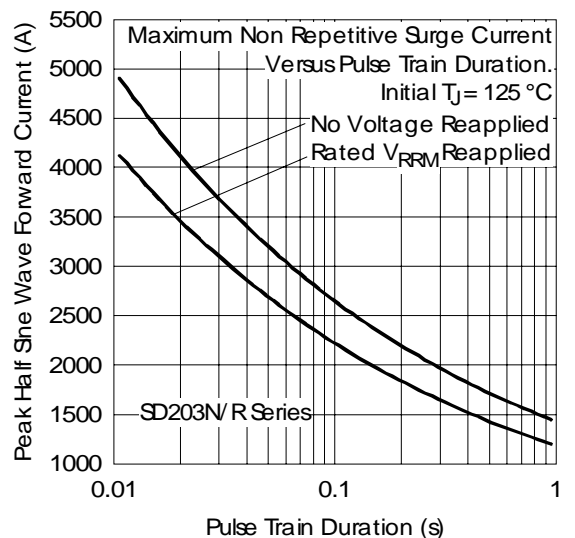


Fig. 6 - Maximum Non-repetitive Surge Current

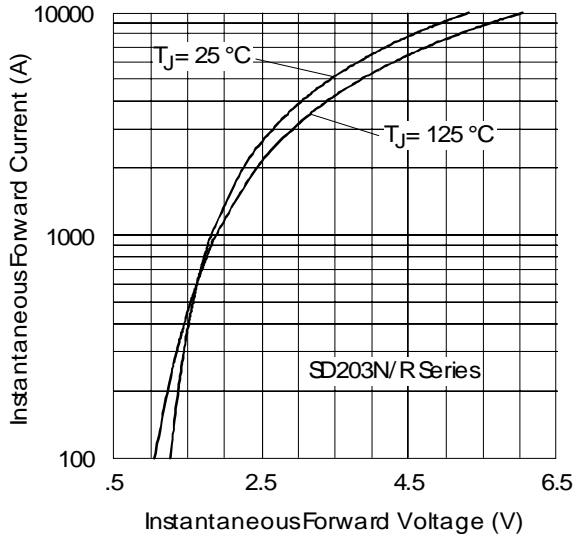


Fig. 7 - Forward Voltage Drop Characteristics

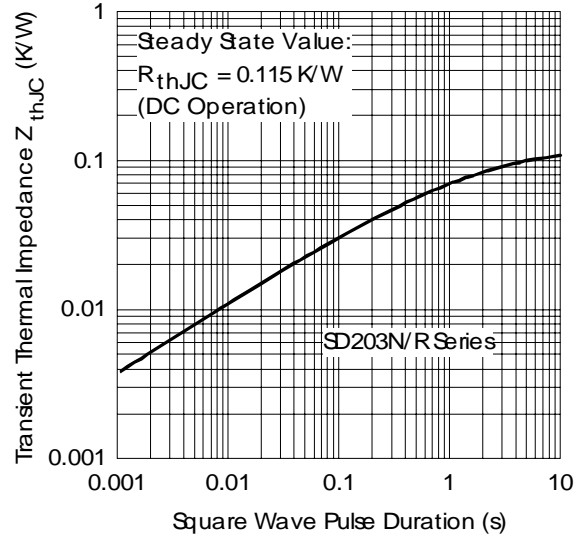


Fig. 8 - Thermal Impedance  $Z_{thJC}$  Characteristic

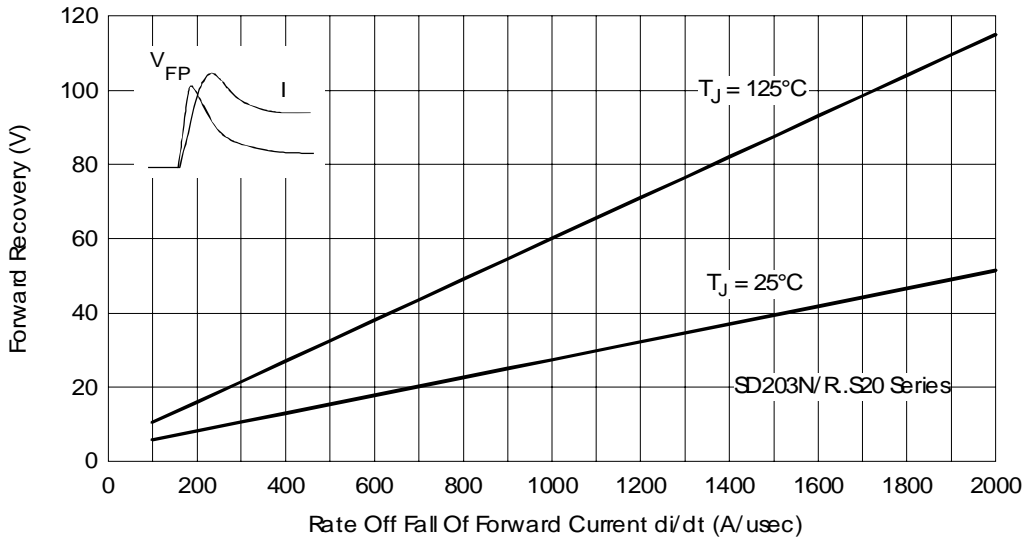


Fig. 9 - Typical Forward Recovery Characteristics

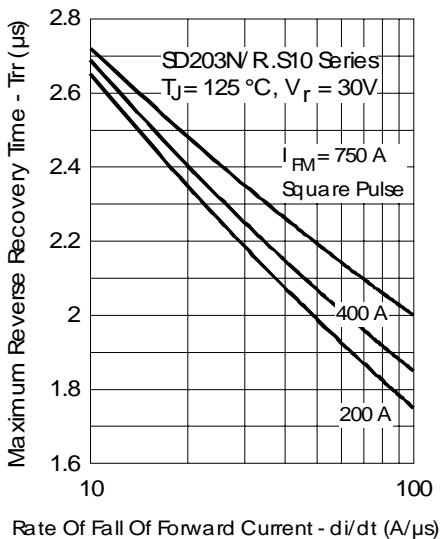


Fig. 10 - Recovery Time Characteristics

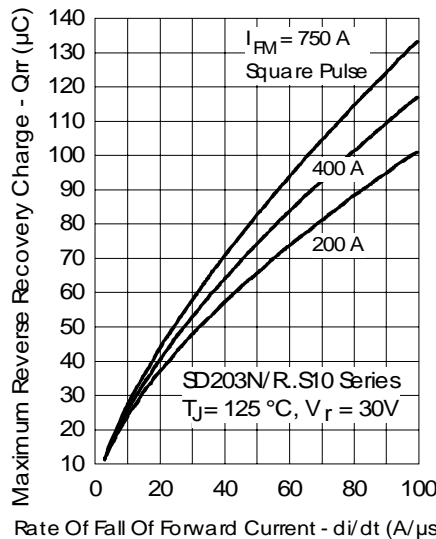


Fig. 11 - Recovery Charge Characteristics

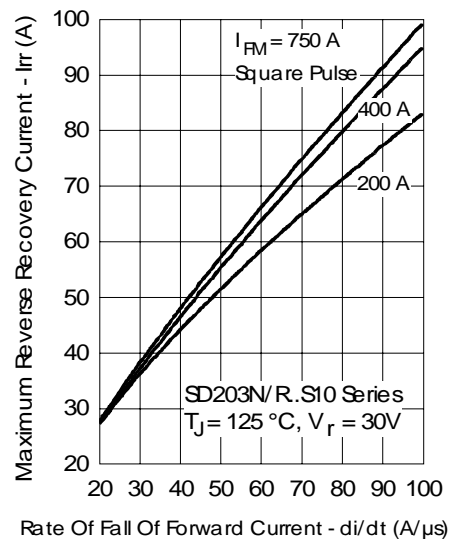


Fig. 12 - Recovery Current Characteristics

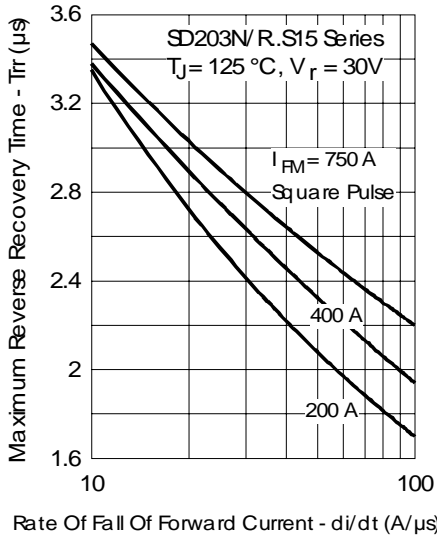


Fig.13 - Recovery Time Characteristics

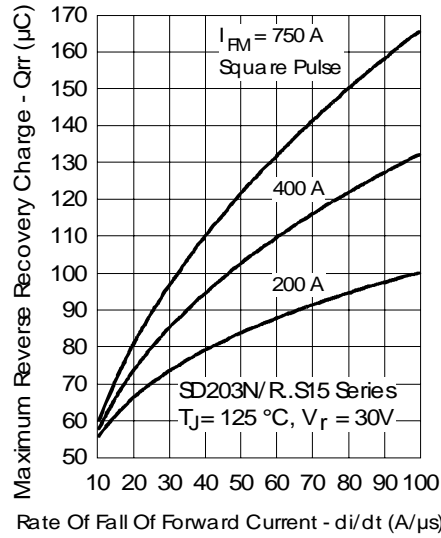


Fig. 14 - Recovery Charge Characteristics

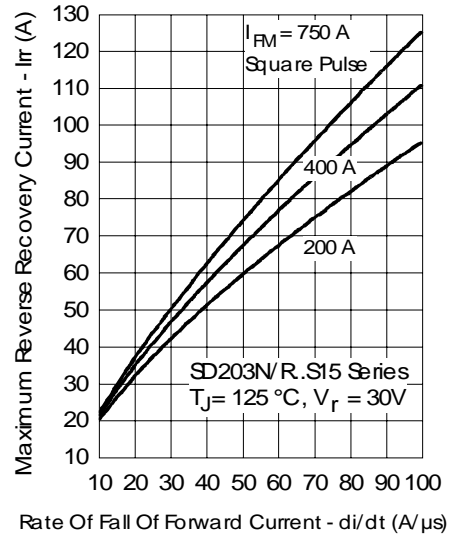


Fig. 15 - Recovery Current Characteristics

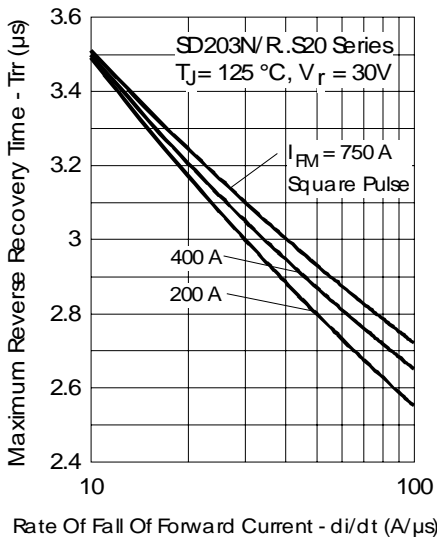


Fig.16 - Recovery Time Characteristics

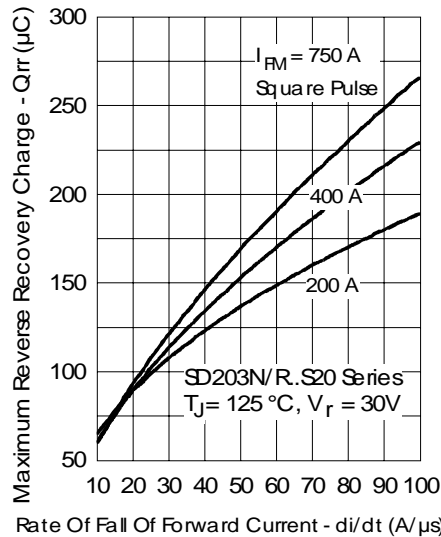


Fig. 17 - Recovery Charge Characteristics

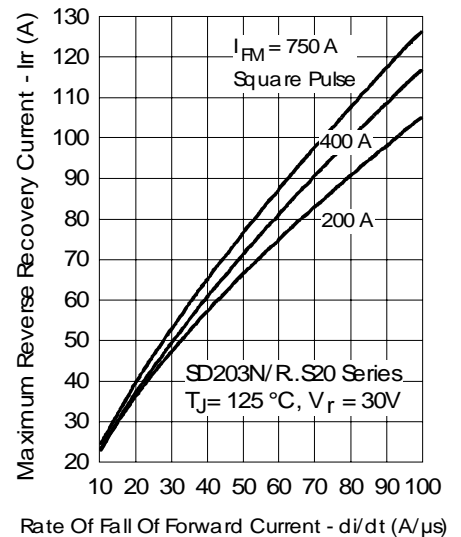


Fig. 18 - Recovery Current Characteristics

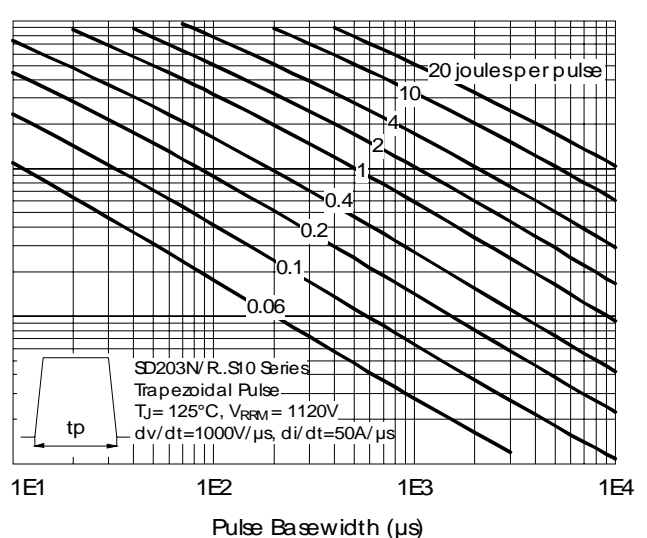
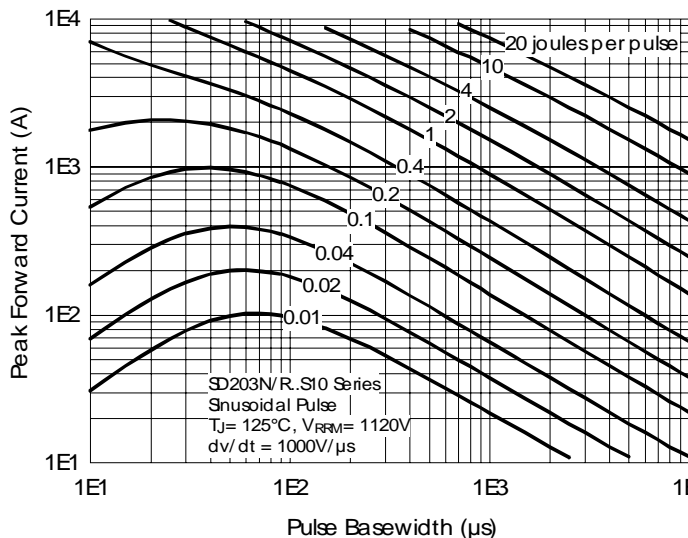


Fig. 19 - Maximum Total Energy Loss Per Pulse Characteristics